

# NPN SILICON RF POWER TRANSISTOR

**DESCRIPTION:**

The **ASI ULBM5** is Designed for Class C, FM Land Mobile Applications up to 470 MHz.

**FEATURES:**

- Common Emitter
- $P_G = 8.5$  dB at 5.0 W/470 MHz
- **Omnigold™** Metalization System

**MAXIMUM RATINGS**

$I_C$	2.0 A
$V_{CBO}$	36 V
$V_{CER}$	18 V
$V_{CES}$	36 V
$V_{EBO}$	4.0 V
$P_{DISS}$	37 W @ $T_C = 25$ °C
$T_J$	-65 °C to +200 °C
$T_{STG}$	-65 °C to +150 °C
$\theta_{JC}$	11.6 °C/W

**PACKAGE STYLE .280 4L STUD**

DIM	MINIMUM Inches / mm	MAXIMUM Inches / mm
A	1.010 / 25.65	1.055 / 26.80
B	.220 / 5.59	.230 / 5.84
C	.270 / 6.86	.285 / 7.24
D	.003 / 0.08	.007 / 0.18
E	.117 / 2.97	.137 / 3.48
F		.572 / 14.53
G		.130 / 3.30
H	.245 / 6.22	.255 / 6.48
I		.640 / 16.26
J	.175 / 4.45	.217 / 5.51
K	.275 / 6.99	.285 / 7.24

**ORDER CODE: ASI10680**

**CHARACTERISTICS**  $T_C = 25$  °C

SYMBOL	TEST CONDITIONS	MINIMUM	TYPICAL	MAXIMUM	UNITS
$BV_{CEO}$	$I_C = 50$ mA	16			V
$BV_{CES}$	$I_C = 10$ mA	36			V
$BV_{EBO}$	$I_E = 2.0$ mA	4.0			V
$I_{CBO}$	$V_{CB} = 15$ V			1.0	mA
$h_{FE}$	$V_{CE} = 5.0$ V $I_C = 200$ mA	20	---	---	---
$C_{ob}$	$V_{CB} = 12$ V $f = 1.0$ MHz	---	19	---	pF
$P_G$	$V_{CC} = 12.5$ V $P_{IN} = 0.70$ W $f = 470$ MHz				dB